Switch-mode Power Rectifier 45 V, 60 A

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 60 A Total (30 A Per Diode Leg)
- Guard-Ring for Stress Protection
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics:

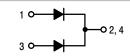
- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams (TO–220) 4.3 Grams (TO–247)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 Units Per Plastic Tube for TO–220 and 30 Units Per Plastic Tube for TO–247



ON Semiconductor®

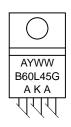
www.onsemi.com

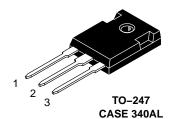
SCHOTTKY BARRIER RECTIFIERS 60 AMPERES, 45 VOLTS













B60L45 = Device Code A = Assembly Location

Y = Year
WW = Work Week
AKA = Polarity Designator
G = Pb-Free Device

ORDERING INFORMATION

Device	Package	Shipping
MBR60L45CTG	TO-220 (Pb-Free)	50 Units/Rail
MBR60L45WTG	TO-247 (Pb-Free)	30 Units/Rail

MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (Rated V_R) $T_C = 145^{\circ}C$ for MBR60L45CTG (Rated V_R) $T_C = 165^{\circ}C$ for MBR60L45WTG		30	А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz)	I _{FRM}	60	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	IFSM	200	А
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Storage Temperature	T _{stg}	-65 to +175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic		Symbol	Value	Unit
Maximum Thermal Resistance (MBR60L45CTG) (MBR60L45WTG)	Junction-to-CaseJunction-to-Case	R _θ JC R _θ JC	1.9 0.59	°C/W

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 2) $ \begin{aligned} &(I_F=30~A,~T_C=25^\circ\text{C})\\ &(I_F=30~A,~T_C=125^\circ\text{C})\\ &(I_F=60~A,~T_C=25^\circ\text{C})\\ &(I_F=60~A,~T_C=125^\circ\text{C}) \end{aligned} $	VF	0.55 0.53 0.73 0.76	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, T _C = 25°C) (Rated DC Voltage, T _C = 125°C)	i _R	1.2 275	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

^{1.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

TYPICAL CHARACTERISTICS

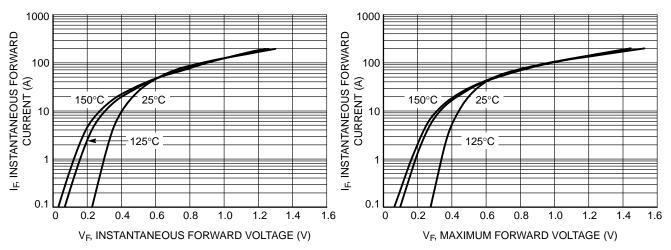


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

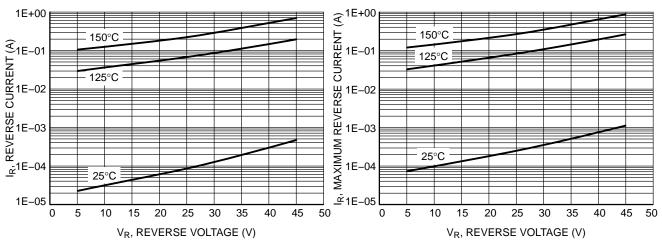


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current

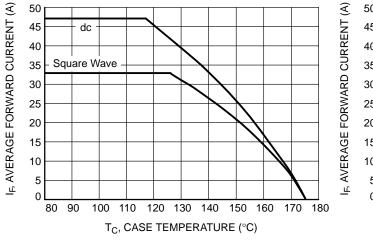


Figure 5. Current Derating for MBR60L45CTG

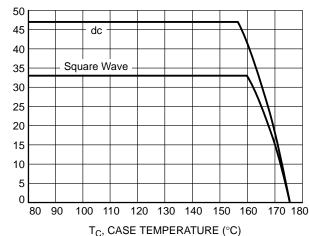


Figure 6. Current Derating for MBR60L45WTG

TYPICAL CHARACTERISTICS

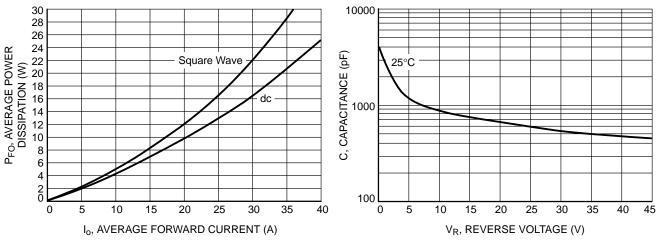


Figure 7. Forward Power Dissipation

Figure 8. Capacitance

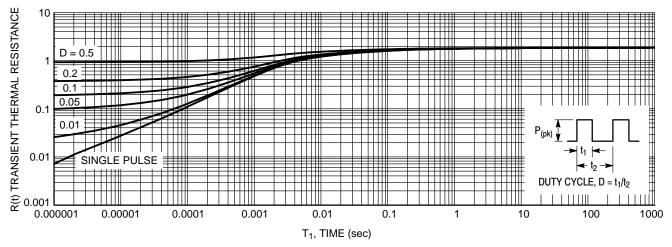


Figure 9. Thermal Response Junction-to-Case for MBR60L45CTG

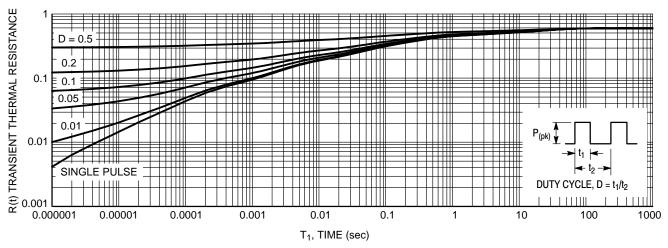
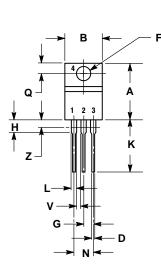
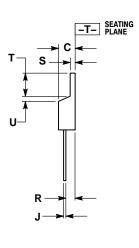


Figure 10. Thermal Response Junction-to-Case for MBR60L45WTG

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH**





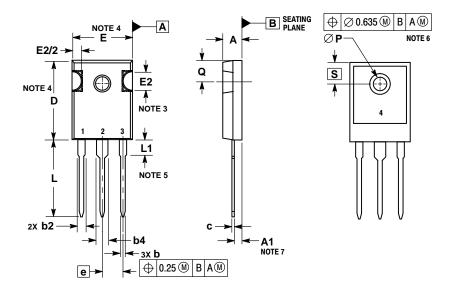
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.415	9.66	10.53
С	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 6:
 PIN 1. ANODE
 2. CATHODE
 3. ANODE
 4. CATHODE

PACKAGE DIMENSIONS

TO-247 CASE 340AL **ISSUE A**



- ES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 SLOT REQUIRED, NOTCH MAY BE ROUNDED.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREME OF THE PLASTIC BODY.
 LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY
- ØP SHALL HAVE A MAXIMUM DRAFT ANGLE OF 1.5° TO THE TOP OF THE PART WITH A MAXIMUM DIAMETER OF 3.91.
 DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED

	51 E.I.			
	MILLIMETERS			
DIM	MIN	MAX		
Α	4.70	5.30		
A1	2.20	2.60		
b	1.00	1.40		
b2	1.65	2.35		
b4	2.60	3.40		
С	0.40	0.80		
D	20.30	21.40		
Е	15.50	16.25		
E2	4.32	5.49		
е	5.45	5.45 BSC		
L	19.80	20.80		
L1	3.50	4.50		
Р	3.55	3.65		
Q	5.40	6.20		
S	6.15 BSC			

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